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June 1999 Revised December 2013

74VCX245

Low Voltage Bidirectional Transceiver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The T/\overline{R} input determines the direction of data flow. The \overline{OE} input disables both the A and B ports by placing them in a high impedance state.

The 74VCX245 is designed for low voltage (1.4V to 3.6V) $\rm V_{CC}$ applications with I/O compatibility up to 3.6V.

The 74VCX245 is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.4V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- Power-off high impedance inpu and juts
- Supports Live Insertion a Vith val (Note 1)
- t_{PD}
 3.5 ns max f 3.0\ 3.6\ V_C
- Static Prive (I_{Oi})_L)
- U. pro, stary no e/EMI reduction circ.
- - man body nodel > 2005v' Machine nodel > 200V
- Leadless DQFN For Free package

in the 1. To ensure the high impedance it to during power up and power down, \overline{OE}_n should be tied to V_{CC} frough a pull up resistor. The minimum value of the hasistor is determined by the current sourcing capability of the

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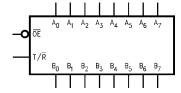
	Oi Number	Package Number	Package Description	
	. (Cλ ¬WM (Λ ⇒ 2)	M20B	20 Le d Small Ovtlir e Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide	
J	7 CX245BQ,′ ote 3)		Po-Free 20-1e.r. inal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 4.5mm	
1	74VCX 245MirC (Note 2	M1C20	20-Leac Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide	

Figure 1-Free package per JEDEC J-STD 127B.

Note 2: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Note 3: DQFN package a rai able in Tape and Reel only,

Logic Symbol



Pin Descriptions

Pin Names	Description
Output Enable Input (Active LOW)	
T/R	Transmit/Receive Input
A ₀ -A ₇	Side A Inputs or 3-STATE Outputs
B ₀ –B ₇	Side B Inputs or 3-STATE Outputs
DAP	No Connect

Note: DAP (Die Attach Pad)

Connection Diagrams Truth Table Pin Assignments for SOIC and TSSOP Inputs Outputs ΟE T/R L Bus B₀-B₇ Data to Bus A₀-A₇ L Н Bus A_0 - A_7 Data to Bus B_0 - B_7 Н Χ HIGH Z State on A₀-A₇, B₀-B₇ (Note 4) H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial $Z = High \ Impedance$ Note 4: Unused bus terminals during HIGH Z Stat LOW. **Logic Diagram** Pin Assignment for DQFN 20 T/R VCC 20 (19 OE A_0 (18 B_0 A_1 (17 B₁ A_2 Аз (16 75 A_4 6 (14 34 A5 (8) J | B5 (12 36 9 GMD (Tor Through View) (3ottom View)

Absolute Maximum Ratings(Note 5)

-0.5V to +4.6V Supply Voltage (V_{CC}) DC Input Voltage (V_I) -0.5V to +4.6V

DC Output Voltage (V_O)

Outputs 3-STATE -0.5V to +4.6V

Outputs Active (Note 6) -0.5V to $V_{CC} + 0.5V$ DC Input Diode Current (I_{IK}) $V_I < 0V$ -50 mA

DC Output Diode Current (I_{OK})

 $V_{O} < 0 \\ V$ -50 mA $V_O > V_{CC}$ +50 mA

DC Output Source/Sink Current

 (I_{OH}/I_{OL}) ±50 mA DC V_{CC} or Ground Current ±100 mA

Storage Temperature (T_{STG}) -65°C to +150°C

Recommended Operating Conditions (Note 7)

Power Supply

1.4V to 3.6V Operating Input Voltage -0.3V to 3.6V

Output Voltage (V_O)

Output in Active States 0V to V_{CC} Output in 3-STATE 0V to 3.6V

Output Current in I_{OH}/I_{OL}

 $V_{CC} = 3.0V \text{ to } 3.6V$

 $V_{CC} = 2.3V \text{ to } 2.7V$ ±18\ $V_{CC} = 1.65V \text{ to } 2.3V$ ±6 r

 $V_{CC} = 1.4V \text{ to } 1.6V$ ιnA

–40°℃ to +85°€ Free Air Operating Temper re (1)

Minimum Input Edg Rate (Δ. 1)

 $V_{IN} = 0.8V + 2.0V$ C = 3.0

Note 5: The Absolut, aximu atings a those values but not be the safety device and a parametric value of the first in the Filterical country in the Filterical not allings of those values be, his which not be need. The divice should not be parametric values a fined in the Electrical oper ad a peralleut value of the little little clinical Chainsistic bles nuaranteed a the boulde Maxim in Pathys. Recumended Operating Condition. "" "able will define a very conditions for all de operation.

Note 6: IO slute Maximum Kating must be observed

'e 7: Floating or unused inputs must be held it. Git or LOW

DC Electrical Characterist

Symbol	Parameter	Condi((o) s	(v)	Min	Max	Units
V _{IH}	HIGH Level In 'age	CONCI	2.7 to 3.3 2.3 to 2.7 65 to 2.3	2.0 1.6 0.65 × V _{CC}		V
V _{IL}	LOW' Inp. ge	11 / C	1.4 to 1.6 2.7 to 3.6	0.65 × V _{CC}	0.8	
VIL.	LOW/ Inp. ge	-01/2	2.7 to 3.0 2.3 to 2.7		0.7	
		CoxIV	1.65 to 2.3		$0.35 \times V_{CC}$	V
			1.4 to 1.6		$0.35 \times V_{CC}$	
V _C	HIGH Leve Output Voltage	$I_{OH} = -1 \overline{10} \mu A$	2.7 to 3.6	V _{CC} - 0.2		
		I _{C 7} = - 12 mA	2.7	2.2		
		i _{OH} = −18 mA	3.0	2.4		
	00/0/5	ı _{OH} = −24 mA	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.3 to 2.7	V _{CC} - 0.2		
		I _{OH} = -6 mA	2.3	2.0		V
		I _{OH} = -12 mA	2.3	1.8		V
	OK.	I _{OH} = -18 mA	2.3	1.7		
		I _{OH} = -100 μA	1.65 to 2.3	V _{CC} - 0.2		
	•	I _{OH} = -6 mA	1.65	1.25		
		I _{OH} = -100 μA	1.4 to 1.6	V _{CC} - 0.2		
		I _{OH} = -2 mA	1.4	1.05		

DC Electrical Characteristics (Continued)

0	B	0	V _{CC}			1111-	
Symbol	Parameter	Conditions	(V)	Min	Max	Units	
V _{OL}	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7 to 3.6		0.2		
		I _{OL} = 12 mA	2.7		0.4		
		I _{OL} = 18 mA	3.0		0.4		
		I _{OL} = 24 mA	3.0		0.55		
		$I_{OL} = 100 \mu A$	2.3 to 2.7		0.2		
		$I_{OL} = 12 \text{ mA}$	2.3		0.4	V	
		$I_{OL} = 18 \text{ mA}$	2.3		.0		
		$I_{OL} = 100 \mu A$	1.65 to 2.3		0.2		~1G1~
		$I_{OL} = 6 \text{ mA}$	1.65		3		, GI
		$I_{OL} = 100 \mu A$	1.4 to 1.6		, T		
		I _{OL} = 2 mA	1.		0.3ხ	() , (
II	Input Leakage Current	$0 \le V_I \le 3.6V$	1.4 to 3		_5.0	μА	
l _{OZ}	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	4 to 3.6		±10	μА	
		$V_I = V_{IH}$ or V_{IL}	+10 3.0			l	
l _{OFF} l	Power-OFF Leakage Current	$0 \le (V_I, V_O) \le 3.6V$			10	μА	
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	1.4 to 3.6		20	μΑ	
		$V_{CC} \le (V_I, V_C)$ 3.6 lote	4 to 3.6	LU"	±20	μΛ	
ΔI_{CC}	Increase in I _{CC} per Input	V _{IH} = V _C oV	2.7 to 3.6		7.0	цA	

Note 8: Outputs disabled or 3-STATE only.

AC Electrical Characteristics Note 9)

Symbol	Paramete [*]	onditions	V _{CC}	A = -40°C	C tc +8',°C	Units	Figure
Oyillboi			(13)	Min	Wax	Omits	Number
t _{PHL} , t _{PLH}	Propagation Delay	C _L 30 pF, R ₁ = £ £ £ £ £ £	3 3 + 0.3	0.6	3.5		Fi
	A_n to B_n f to A_n	. Olh, ×	2.5 ± 0.2	0.8	4.2		Figures 1, 2
		(O) (C)	1.8 ± 0.15	1.5	8.4	ns	,
		C _L = 15 /JF, R _L = 2 \tag{2}	1.7± 0.1	1.0	16.8		Figures 5, 6
t _{PZI} z _H	Output 'No.T'	$C_L = 30 \text{ pF}, \Gamma_L = 500\Omega$	3.3 ± 0.3	0.6	4.5		Fi
		01, 16,	2.5 ± 0.2	0.8	5.6		Figures 1, 3, 4
			1.8 ± 0.15	1.5	9.8	ns	., -, -
	GROKE	$C_L = 15 \text{ pF}, \ \kappa_L = 2.1\Omega$	1.5 ± 0.1	1.0	19.6	•	Figures 5, 7, 8
PLZ, HZ	Outpu Disable Time	$C = 20 p , R_L = 500\Omega$	3.3 ± 0.3	0.6	3.6		Fi
			2.5 ± 0.2	0.8	4.0		Figures 1, 3, 4
()			1.8 ± 0.15	1.5	7.2	ns	, -,
710	Pr. F.S.	$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	14.4		Figures 5, 7, 8
OSHL	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3		0.5		
toslh	(Note 10)		2.5 ± 0.2		0.5	ns	
	OK.		1.8 ± 0.15		0.75		
	C	$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5	•	

Note 9: For $C_L = 50_P F$, add approximately 300 ps to the AC maximum specification.

Note 10: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{cc}	$T_A = 25^{\circ}C$	Units	
Cymbol	T drameter	Conditions	(V)	Typical]	
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF, } V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.3		
			2.5	0.7	V	
			3.3	1.0		
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF, } V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.3		
			2.5	-0.7	V	
			3.3	-1.0		
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.3		
			2.5	1		
			3.3	2.		

Capacitance

Symbol
C _{IN}
C _{I/O}
C _{PD}
DEV

AC Loading and Waveforms (V $_{CC}$ 3.3V \pm 0.3V to 1.8V \pm 0.15V)

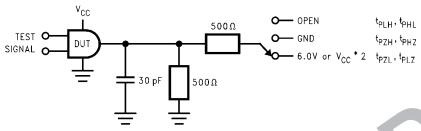


FIGURE 1. AC Test Circuit

TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at $V_{CC} = 3.3V \pm 0.3V$;
	V_{CC} x 2 at V_{CC} = 2.5V ± 0. 1.8V ± '5V
t _{PZH} , t _{PHZ}	Ğ,



FIGURE 2. W. You. verting and Non-Inverting Functions

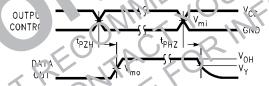
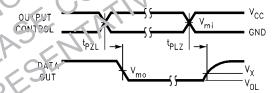


FIGURE 3.3-STATE Output High Enable and Disable Times for Low Voltage Logic



FIC UP.E 1. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

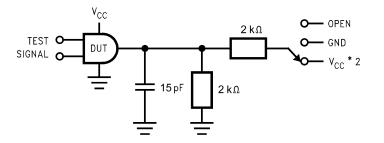
Symbol	V _{cc}				
Cymbol	3.3V ± 0.3V	2.5V ± 0.2V	1.8V ± 0.15V		
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2		
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2		
V _X	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V		
V _Y	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V		

 t_{PLH}, t_{PHL}

 t_{PZH}, t_{PHZ}

 t_{PZL}, t_{PLZ}

AC Loading and Waveforms (V_{CC} 1.5 \pm 0.1V)

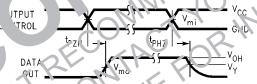


TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t_{PZL}, t_{PLZ}	V_{CC} x 2 at V_{CC} = 1.5V \pm 0.1V
t _{PZH} , t _{PHZ}	GND

FIGURE 5. AC Test Circuit



FIGURE vefc for . ing and Nur-Inverting Functions



F URE 7. 3-5 (A) E Output !iig. Enable and D sab!a Times for Low Voltage Logic

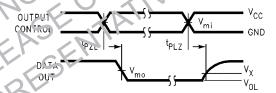


FIGURE 2. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

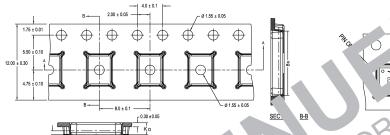
Symbol	V _{CC}
Symbol	1.5V ± 0.1V
V _{mi}	V _{CC} /2
V _{mo}	V _{CC} /2
V _X	V _{OL} + 0.1V
V _Y	V _{OH} – 0.1V

Tape and Reel Specification

Tape Format for DQFN

Package	Tape	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
BQX	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

TAPE DIMENSIONS inches (millimeters)



PK SIL.	IM.Ao	ΓιΜ.L'o	DIM.Ko
3.5 1.5	J.8 ± 0.1	1.0 ± 0.1	0.9 (1
<u>0λ</u>	3.3 ± 0.1	3.3 ± 0.1	(15) ± 0.1
X 4.5	2.ε ± 0.1	4.8 ± 0.1	- 6.0 ± 0.1
2 X 3.5	2.3 ± 5.1	3.8 ± u.1	0.9 ± 0.1
2.5 X 3 5	2.8 ± 0.1	?.5 t 7.1	0.9 ± (1
2.5 X ?.:	2.8 ± 0.1	2 º ± 0.1	Q.9 <u>1</u> Q 1
2.5 X 3 ½ 2.5 X ?.5		29 ± 0.1	

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NOTES: unless otherwise

- r feeding h 1. Cummulative pitcl
- 2. Smallest allowable 3. Thru b ca nding radius
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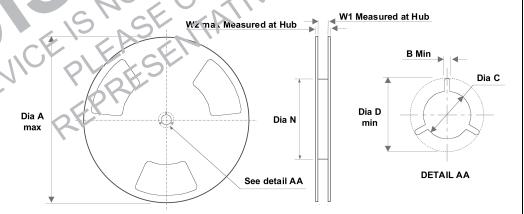
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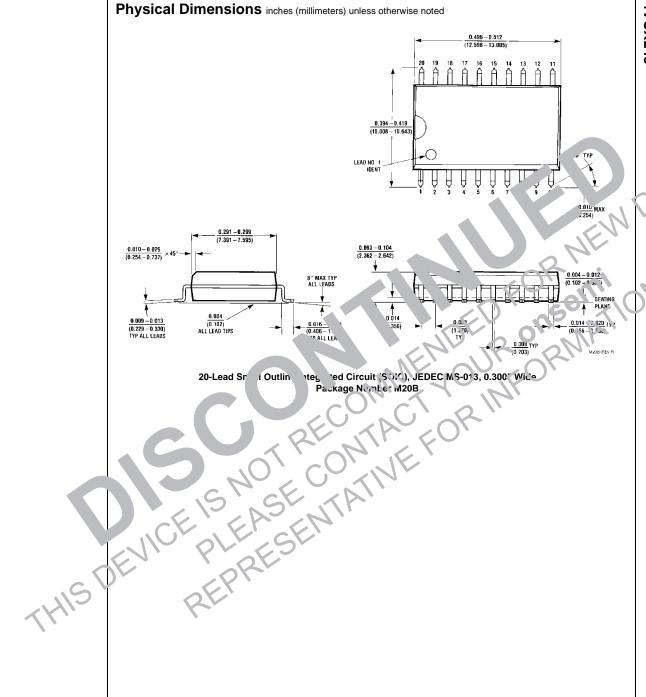
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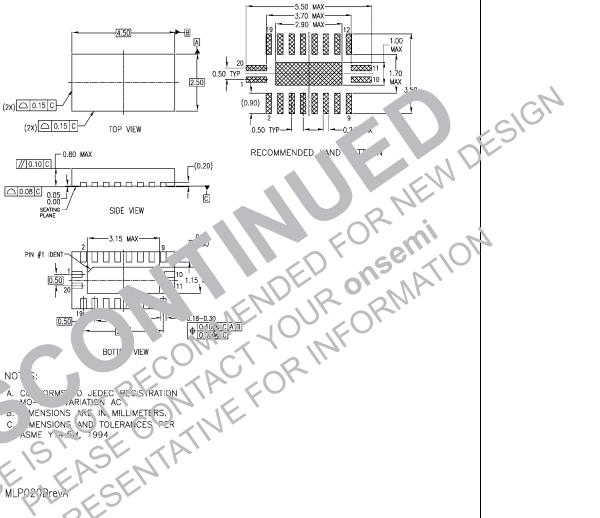
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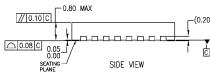


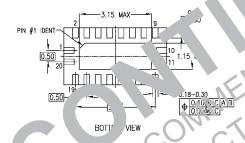
Tape Size	Α	В	С	D	N	W1	W2
12 mm	13.0	0.059	0.512	0.795	2.165	0.488	0.724
	(330.0)	(1.50)	(13.00)	(20.20)	(55.00)	(12.4)	(18.4)



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





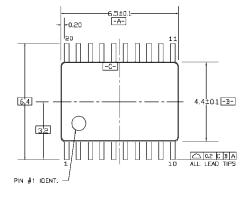


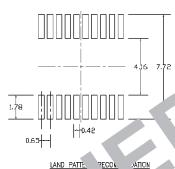
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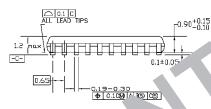
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Pb-Free 20-Ts/m, al Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 4.5mm Package Number MLP020B

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)









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MIL20REYD1

20-Lead Thin S wink Small C will e Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC20

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